

# **DESCRIPTION**

The SPN5001 is the N-Channel enhancement mode power field effect transistor which is produced with high voltage MOS technology. This device is particularly suited for reducing the no load consumption in PC power, TV power and Adapter.

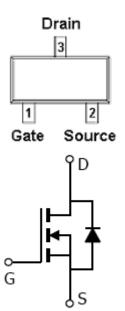
# **APPLICATIONS**

- Desk PC Power Supply
- AC adapter
- LCD TC Power Supply

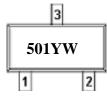
# **FEATURES**

- 600V/27mA, RDS(ON)= $300\Omega$ @VGS=10V
- ◆ Super high density cell design for extremely low RDS(ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ SOT-23 package design

# PIN CONFIGURATION(SOT-23)



#### PART MARKING



**YW: Date Code** 

PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

# ORDERING INFORMATION

Part Number	Package	Part Marking
SPN5001S23RGB	SOT-23	501

<sup>※</sup> SPN5001S23RGB: Tape Reel; Pb − Free; Halogen − Free

# **ABSOULTE MAXIMUM RATINGS** (TA=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	600	V	
Gate –Source Voltage - Continuous		VGSS	±20	V	
Continuous Drain Current	TA=25°C	ID	27	mA	
Power Dissipation	Ta=25°C	PD	0.5	W	
Operating Junction Temperature		Tı	<b>-</b> 55 ∼ 150	$^{\circ}\!\mathbb{C}$	
Storage Temperature Range		Tstg	<b>-</b> 55 ∼ 150	$^{\circ}\!\mathbb{C}$	
Thermal Resistance-Junction to Ambient		R <sub>θ</sub> JA	250	°C/W	

ELECTRICAL CHARACTERISTICS (TA=25°C Unless otherwise noted)								
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit		
Static				•	•			
Drain-Source Breakdown Voltage	V(BR)DSS	V <sub>G</sub> s=0V,I <sub>D</sub> =250uA	600			V		
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	3.0		4.5			
Gate Leakage Current	Igss	VDS=0V,VGS=±20V			±100	nA		
Zero Gate Voltage Drain Current	IDSS	VDS=480V,VGS=0V TJ=25°C			25	uA		
Drain-Source On-Resistance	RDS(on)	V <sub>G</sub> s=10V,I <sub>D</sub> =16mA			300	Ω		
Forward Transconductance	Gfs	$V_{DS} = 10 \text{ V}, I_{D} = 16 \text{mA}$		28		mS		
Diode Forward Voltage	Vsd	Is = 50 mA, VGS = 0V		0.8	1.5	V		
Dynamic								
Total Gate Charge	Qg	$V_{DD} = 200 \text{ V}, I_{D} = 0.1 \text{ A}, V_{GS} = 10 \text{ V}$	1.8	2.5	3.2	nC		
Gate-Source Charge	Qgs			1.3				
Gate-Drain Charge	Qgd	V G S 10 V		0.8				
Input Capacitance	Ciss	$V_{DS} = 25 \text{ V, } f = 1 \text{ MHz,}$ $V_{GS} = 0$	8.8	12.5	16.2	pF		
Output Capacitance	Coss		7	10	13			
Reverse Transfer Capacitance	Crss		5	7	9			
Turn-On Time	td(on)	V <sub>DS</sub> = 300 V, I <sub>D</sub> = 10m A		11.5		nS		
	tr			14.5				
Turn-Off Time	td(off)	$R_G = 3.3\Omega \text{ V}_{GS} = 10.0 \text{ V}$ $R_D = 30k\Omega$		14				
	tf			120				

# TYPICAL CHARACTERISTICS

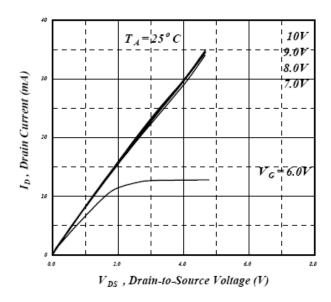
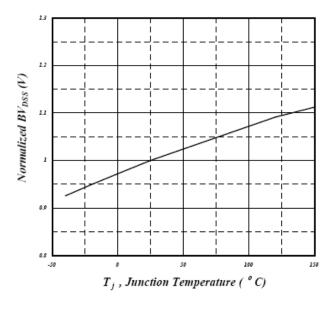


Fig 1. Typical Output Characteristics



 $\label{eq:continuous_problem} \begin{tabular}{ll} Fig 3. Normalized BV_{DSS} & v.s. Junction \\ Temperature \\ \end{tabular}$ 

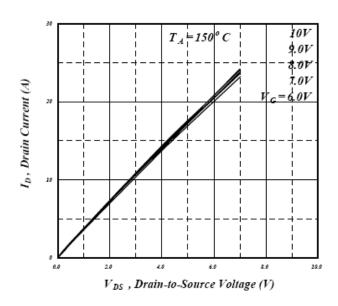


Fig 2. Typical Output Characteristics

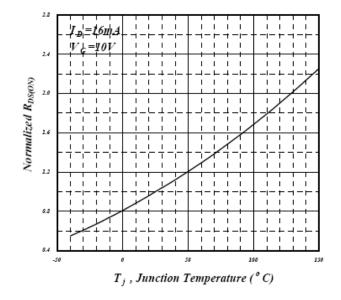


Fig 4. Normalized On-Resistance v.s. Junction Temperature

# TYPICAL CHARACTERISTICS

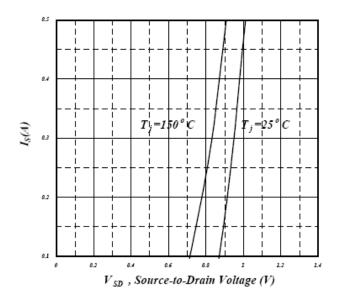


Fig 5. Forward Characteristic of Reverse Diode

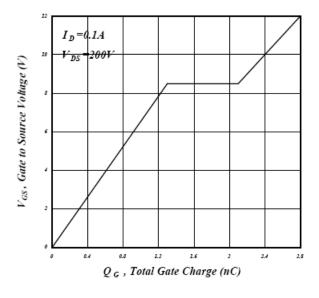


Fig 7. Gate Charge Characteristics

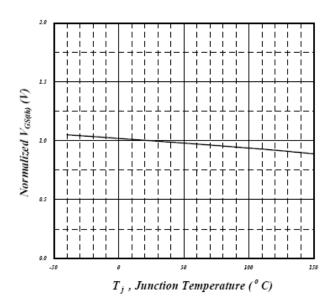


Fig 6. Gate Threshold Voltage v.s. Junction Temperature

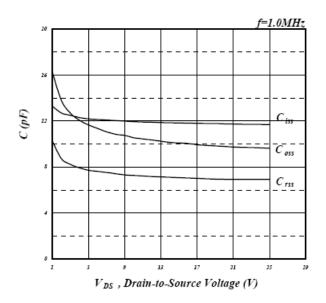


Fig 8. Typical Capacitance Characteristics

# TYPICAL CHARACTERISTICS

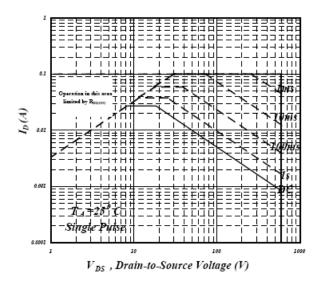


Fig 9. Maximum Safe Operating Area

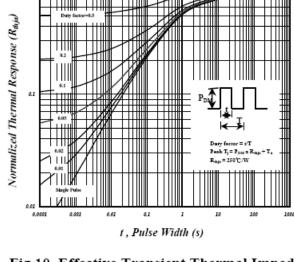


Fig 10. Effective Transient Thermal Impedance

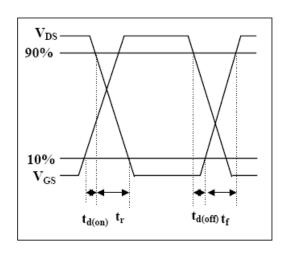


Fig 11. Switching Time Waveform

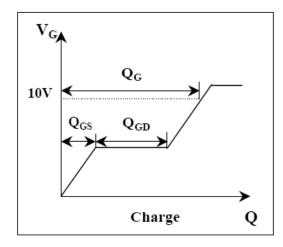


Fig 12. Gate Charge Circuit

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